NSN 5961-01-185-9487

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-185-9487 **Inclosure Material:** Metal **Overall Length:** 1.438 inches **End Application:** Radar system an/fps-117 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.677 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 working peak reverse voltage and 45.0 reverse voltage, instantaneous and 54.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 150.00 amperes source cutoff current absolute and 75.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: